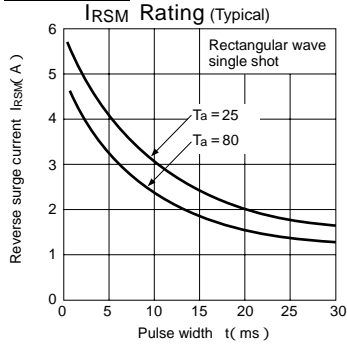


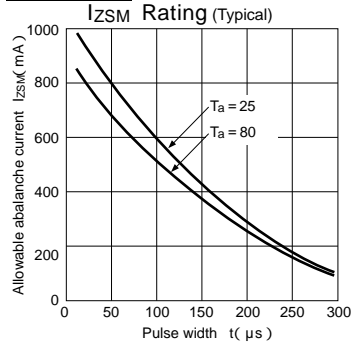
Avalanche Diodes

Parameter Type No.	Absolute Maximum Ratings				Electrical Characteristics (Ta = 25)						Others		
	V _{RM} (V)	I _{ZSM} (A) Rectangular wave single shot	T _j ()	T _{stg} ()	V _Z (V) I _Z = 1mA Instantaneous	I _R (μ A) V _R = V _{RM}	I _{R(H)} (μ A) V _R = V _{RM}	J (V/) I _Z = 1mA	Z (%/) I _Z = 1mA	R _Z () I _Z = 0.5 ~ 1.5A	Mass (g)	Application	Fig.
RM 25	40	3.0(10ms)	- 40 to + 130		50 to 61.5	5.0	20 (Ta = 80)	-	0.09typ	5max	0.44	Surge absorbers	Ⓐ
RM 26	50				60 to 70								
R 2M	130	1.0(100 μ s)	- 40 to + 150		135 to 180	10	50 (Ta = 100)						
RY 23	200	0.1(100 μ s)	- 40 to + 130		250 to 400		50 (Ta = 80)						
RY 24	400			400 to 450									

RM 25, 26



RY 23, 24



External Dimensions

(Unit: mm)

Flammability:
UL94V-0 or Equivalent

Fig. Ⓐ

